SMAF Plastic-Encapsulate Diodes

High Efficient Rectifier

Features

- I_O 2A
- VRRM 50V-1000V
- High surge current capability
- Glass passivated chip
- Polarity: Color band denotes cathode

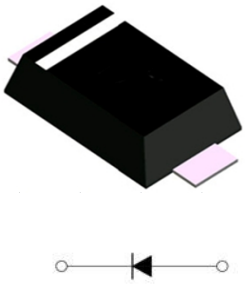
Applications

- Rectifier

Marking

- US2AF-US2MF ： US2A-US2M

SMAF



Limiting Values (Absolute Maximum Rating)

Item	Symbol	Unit	Test Conditions	US2							
				AF	BF	DF	FF	GF	JF	KF	MF
Repetitive Peak Reverse Voltage	V_{RRM}	V		50	100	200	300	400	600	800	1000
Maximum RMS Voltage	V_{RMS}	V		35	70	140	210	280	420	560	700
Average Forward Current	$I_{F(AV)}$	A	60HZ Half-sine wave, Resistance load, TL =110℃	2.0							
Surge(Non-repetitive)Forward Current	I_{FSM}	A	60Hz Half-sine wave ,1 cycle , Ta =25℃	50							
Junction Temperature	T_J	℃		-55~+150							
Storage Temperature	T_{STG}	℃		-55~+150							

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Electrical Characteristics (T_a=25℃ Unless otherwise specified）

Item	Symbol	Unit	Test Condition		US2							
					AF	BF	DF	FF	GF	JF	KF	MF
Peak Forward Voltage	V_F	V	I_F=2.0A		1.0			1.3		1.7		
Maximum reverse recovery time	t_{rr}	ns	I_F=0.5A,I_R=1.0A,I_{rr}=0.25A		50					75		
Peak Reverse Current	I_{RRM1}	μA	V_{RM}=V_{RRM}	T_a =25℃	5.0							
	I_{RRM2}			T_a =100℃	100							
Thermal Resistance(Typical)	$R_{\theta J-A}$	℃/W	Between junction and ambient		80[1)]							
	$R_{\theta J-L}$		Between junction and terminal		20[1)]							

Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

Typical Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

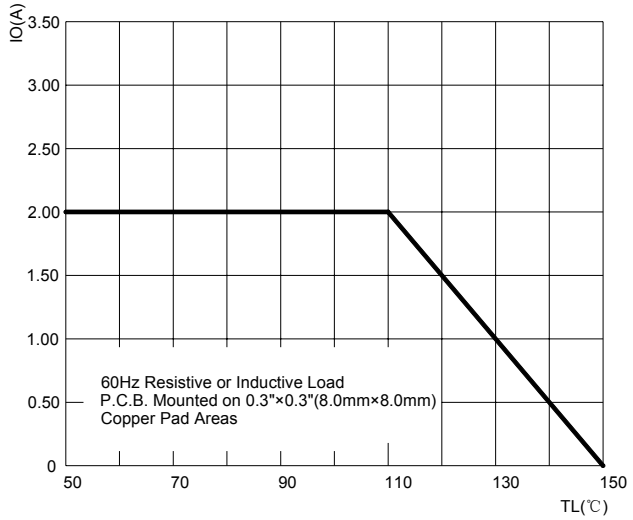


FIG.2: MAXIMUM NON-REPETITIVE FORWARD URGE CURRENT

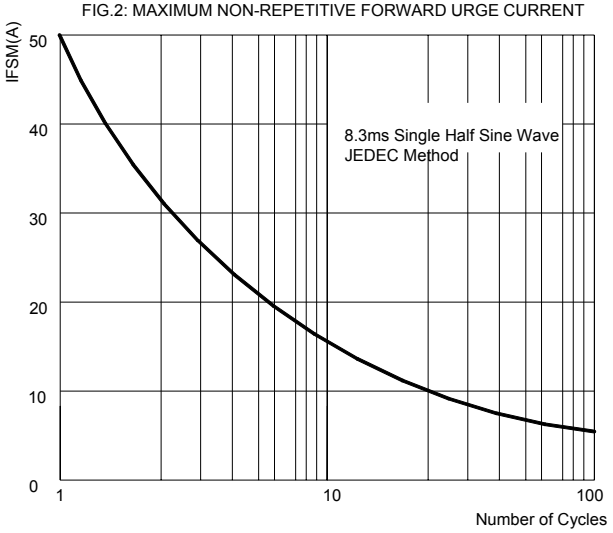
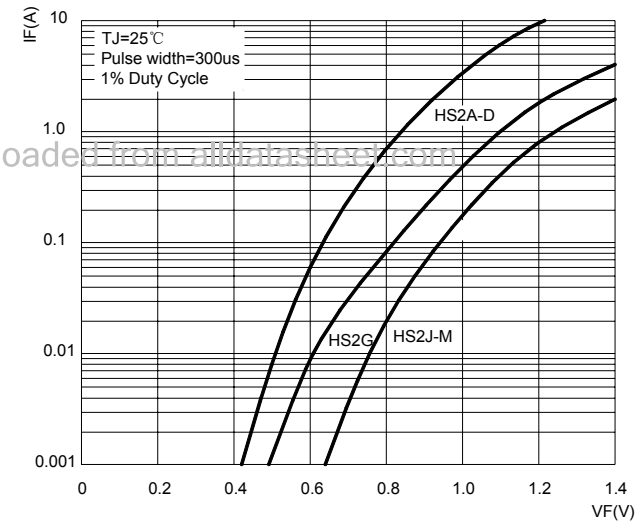


FIG.3: TYPICAL FORWARD CHARACTERISTICS



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FIG.4：TYPICAL REVERSE CHARACTERISTICS

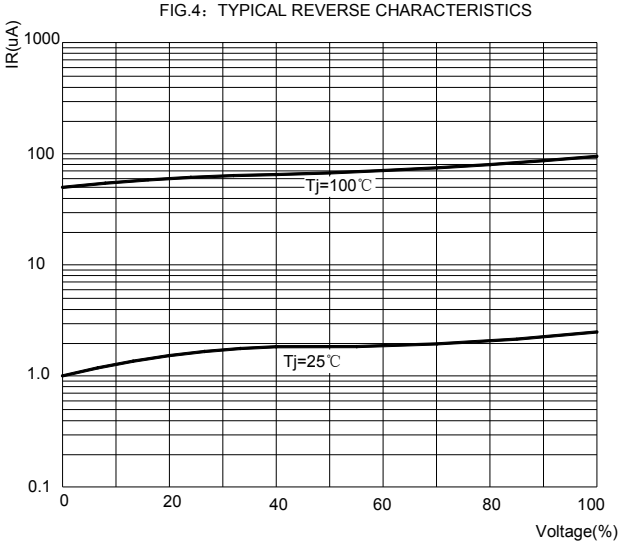
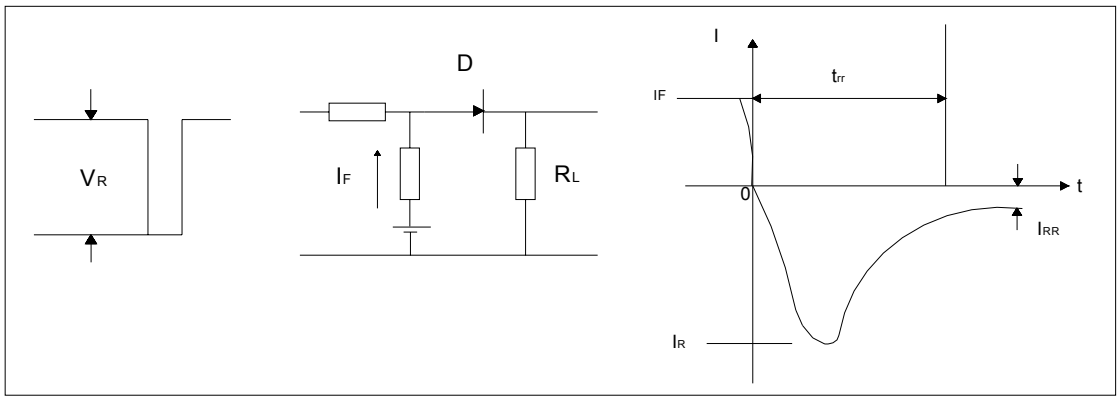
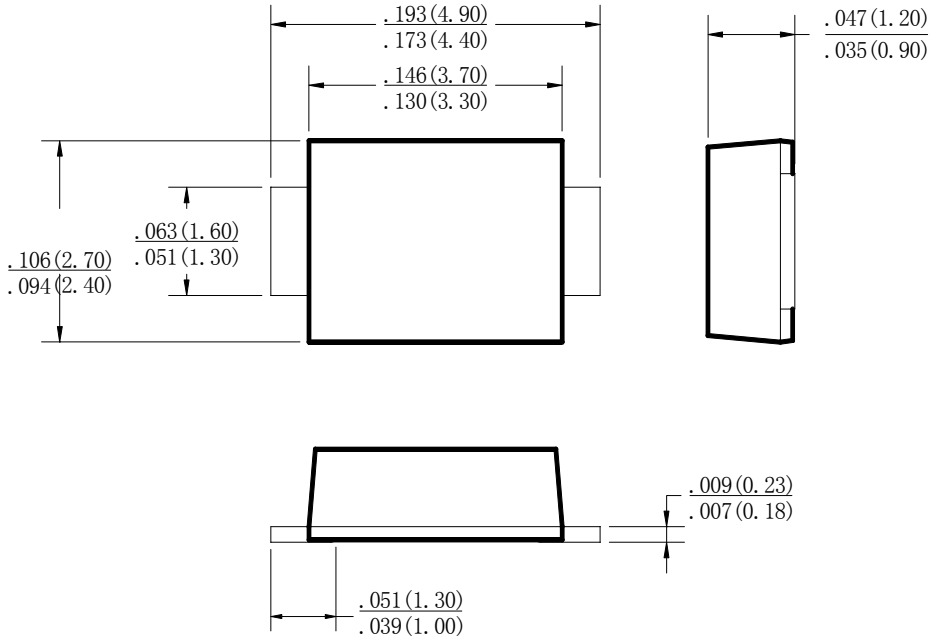


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time



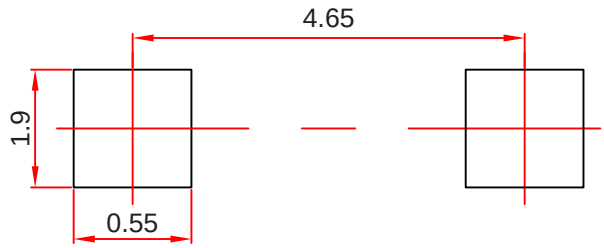
SMAF Package Outline Dimensions



Dimensions in inches and (millimeters)

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SMAF Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.

NOTICE

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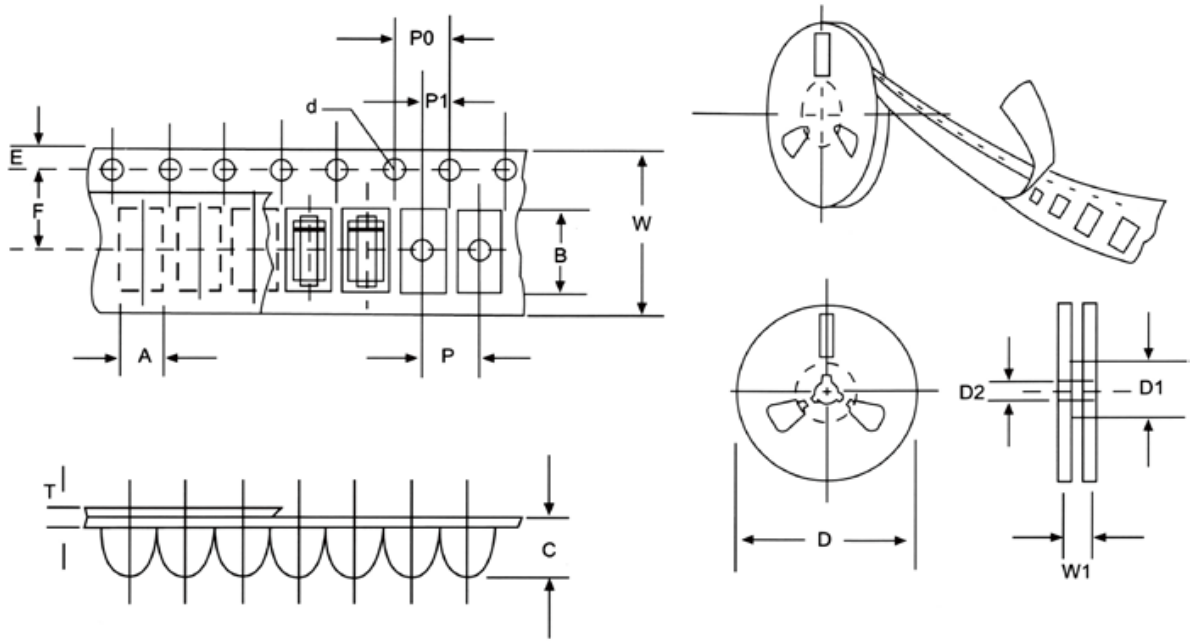


FIG:CONFIGURATION OF AXIAL TAPING

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ITEM	SYMBOL	SMAF mm(inch)
Carrier width	A	2.83+0.1(0.112+0.004)
Carrier length	B	4.90+0.1(0.193+0.004)
Carrier depth	C	1.45+0.1(0.057+0.004)
Sprocket hole	d	1.55+0.05(0.061+0.002)
Reel outside diameter	D	280/178+2.0(11/7.0+0.079)
Reel inner diameter	D1	8.0+0.2(0.315+0.008)
Feed hole diameter	D2	13+0.5(0.512+0.020)
Stroket hole position	E	1.75+0.1(0.069+0.004)
Punch hole position	F	5.5+0.05(0.217+0.002)
Punch hole pitch	P	4.0+0.1(0.157+0.004)
Sprocket hole pitch	P0	4.0+0.1(0.157+0.004)
Embossment center	P1	2.0+0.1(0.079+0.004)
Totall tape thickness	T	0.23-0.29(0.009-0.011)
Tape width	W	12.0+0.1(0.472+0.004)
Reel width	W1	16.8+2.0(0.661+0.079)

NOTE:Devices are packde in accordance with EIA standard RS-481-A and specification given above.